

**FEATURES**

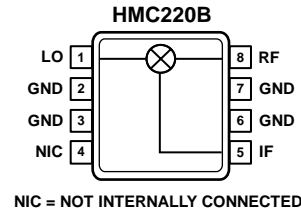
**Low conversion loss: 9 dB**  
**No dc bias and no external matching required**  
**Ideal for upconversion and downconversion**  
**Wideband IF range: DC to 4 GHz**  
**Ultrasmall package: 8-Lead MINI\_SO\_EP**

**APPLICATIONS**

**Very small aperture terminals (VSAT) and mobile satellite communication terminals**  
**Microwave and military radio**  
**Wireless backhaul equipment**  
**Automotive, dedicated short range communications (DSRC) and intelligent vehicle highway systems (IVHS)**  
**Military radar, electronic warfare (EW), and electronic counter measure (ECM) subsystems**

**GENERAL DESCRIPTION**

The HMC220B is an ultraminiature, double-balanced mixer in an 8-lead mini small outline package with exposed pad (MINI\_SO\_EP). This fundamental, monolithic microwave integrated circuit (MMIC) mixer is constructed of gallium arsenide (GaAs) Schottky diodes and planar transformer baluns on the chip.

**FUNCTIONAL BLOCK DIAGRAM***Figure 1.*

The device can be used as an upconverter, downconverter, biphas demodulator, or phase comparator from 5 GHz to 12 GHz. The HMC220B provides excellent local oscillator (LO) to radio frequency (RF) and LO to intermediate frequency (IF) isolation due to optimized balun structures and operates as low as 7 dBm. The RoHS compliant HMC220B eliminates the need for wire bonding and is compatible with high volume surface-mount manufacturing techniques.

# HMC220B\* PRODUCT PAGE QUICK LINKS

Last Content Update: 07/30/2017

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## COMPARABLE PARTS

View a parametric search of comparable parts.

## DOCUMENTATION

### Data Sheet

- HMC220B: 5 GHz to 12 GHz GaAs, MMIC, Fundamental Mixer Data Sheet

## DESIGN RESOURCES

- HMC220B Material Declaration
- PCN-PDN Information
- Quality And Reliability
- Symbols and Footprints

## DISCUSSIONS

View all HMC220B EngineerZone Discussions.

## SAMPLE AND BUY

Visit the product page to see pricing options.

## TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

## DOCUMENT FEEDBACK

Submit feedback for this data sheet.

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## REVISION HISTORY

7/2017—Revision 0: Initial Version

## SPECIFICATIONS

$T_A = 25^\circ\text{C}$ , IF = 100 MHz, LO drive level = 10 dBm. All measurements performed as a downconverter with the lower sideband selected, unless otherwise noted.

**Table 1.**

Parameter	Symbol	Min	Typ	Max	Unit
FREQUENCY RANGE					
Radio Frequency	RF	5		12	GHz
Local Oscillator	LO	5		12	GHz
Intermediate Frequency	IF	DC		4	GHz
LO DRIVE LEVEL					
		7	10		dBm
PERFORMANCE AT LO DRIVE = 10 dBm					
Conversion Loss			9	12	dB
Single Sideband (SSB) Noise Figure	NF		9		dB
Input Third-Order Intercept	IIP3	12	17		dBm
Input Second-Order Intercept	IIP2		50		dBm
Input 1 dB Compression Point	IP1dB		9.5		dB
PERFORMANCE AT LO DRIVE = 13 dBm					
Conversion Loss			9	13	dB
SSB Noise Figure	NF		10		dB
Input Third-Order Intercept	IIP3	12	18.5		dBm
Input Second-Order Intercept	IIP2		60		dBm
Input 1 dB Compression Point	IP1dB		11		dB
ISOLATION					
RF to IF			20		dB
LO to RF		49	57		dB
LO to IF		23	38		dB

## ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
RF Input Power	25 dBm
LO Input Power	25 dBm
IF Input Power	25 dBm
IF Source and Sink Current	3 mA
Continuous Power Dissipation, P <sub>DISS</sub> (T <sub>A</sub> = 85°C, Derate 10.81 mW/°C Above 85°C)	211 mW
Maximum Junction Temperature	130°C
Maximum Peak Reflow Temperature (MSL1) <sup>1</sup>	235°C
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	-65°C to +125°C
Electrostatic Discharge (ESD) Sensitivity	
Human Body Model (HBM)	2000 V (Class 2)
Field Induced Charged Device Model (FICDM)	750 V (Class C4)

<sup>1</sup> See the Ordering Guide section.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

## THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

Table 3. Thermal Resistance

Package Type	$\theta_{JA}$	$\theta_{JC}$	Unit
RH-8-3 <sup>1</sup>	104.7	300	°C/W

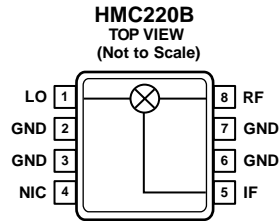
<sup>1</sup> Thermal impedance simulated values are based on JEDEC 2S2P test board with 3 x 3 thermal vias. See JEDEC JESD51-12 for additional information.

## ESD CAUTION



**ESD (electrostatic discharge) sensitive device.** Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# PIN CONFIGURATION AND FUNCTION DESCRIPTIONS



- NOTES**
1. NIC = NOT INTERNALLY CONNECTED. THIS PIN CAN BE LEFT FLOATING OR IT CAN BE SOLDERED DOWN TO RF/DC GND. THE NIC PIN DOES NOT AFFECT THE PERFORMANCE OF THE HMC220B.
  2. EXPOSED PAD. CONNECT THE EXPOSED PAD TO A LOW IMPEDANCE THERMAL AND ELECTRICAL GROUND PLANE.

15769-002

Figure 2. Pin Configuration

Table 4. Pin Function Descriptions

Pin No.	Mnemonic	Description
1	LO	Local Oscillator. This pin is ac-coupled and matched to 50 Ω. See Figure 4 for the LO interface schematic.
2, 3, 6, 7	GND	Ground. Connect the package bottom to RF/dc ground. See Figure 3 for the GND interface schematic.
4	NIC	Not Internally Connected. This pin can be left floating or it can be soldered down to RF/dc GND. The NIC pin does not affect the performance of the HMC220B.
5	IF	Intermediate Frequency. This pin is dc-coupled. For applications not requiring operations to dc, dc block this port externally using a series capacitor whose value is chosen to pass the necessary IF frequency range. For operation to dc, this pin must not source or sink 3 mA of current, or the device is nonfunctioning and possible device failure may result. See Figure 5 for the IF interface schematic.
8	RF EPAD	Radio Frequency. This pin is ac-coupled internally and match to 50 Ω. See Figure 6 for the RF interface schematic. Exposed Pad. Connect the exposed pad to a low impedance thermal and electrical ground plane.

## INTERFACE SCHEMATICS



Figure 3. GND Interface Schematic

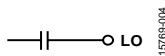


Figure 4. LO Interface Schematic

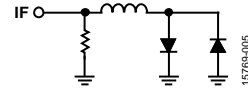


Figure 5. IF Interface Schematic

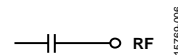


Figure 6. RF Interface Schematic

# TYPICAL PERFORMANCE CHARACTERISTICS

## DOWNCONVERTER PERFORMANCE

### Downconverter Performance at IF = 100 MHz, Lower Sideband

Data taken at LO = 10 dBm, T<sub>A</sub> = 25°C, unless otherwise noted.

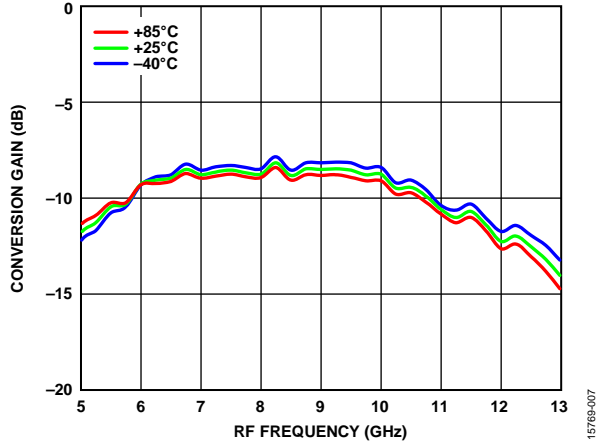


Figure 7. Conversion Gain vs. RF Frequency at Various Temperature

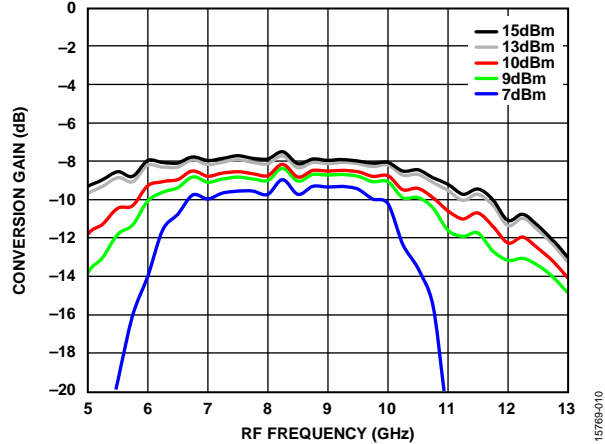


Figure 10. Conversion Gain vs. RF Frequency at Various LO Powers

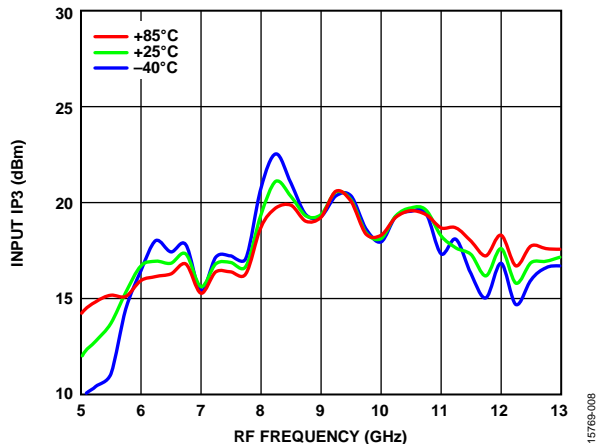


Figure 8. Input IP3 vs. RF Frequency at Various Temperatures

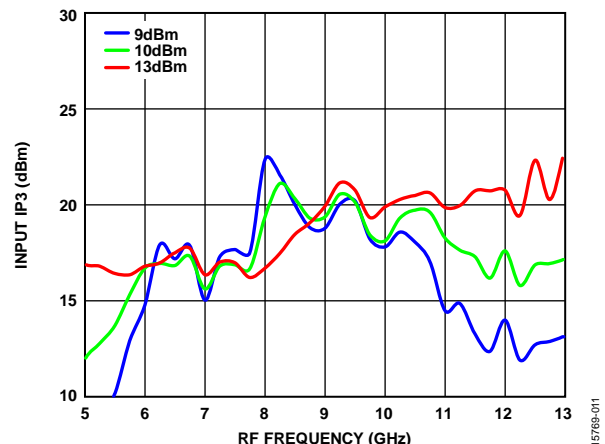


Figure 11. Input IP3 vs. RF Frequency at Various LO Powers

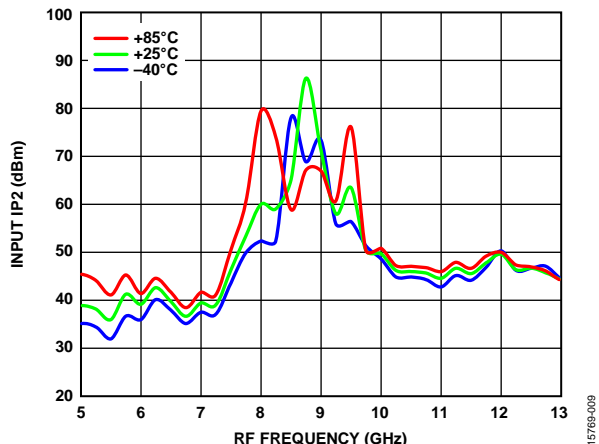


Figure 9. Input IP2 vs. RF Frequency at Various Temperatures

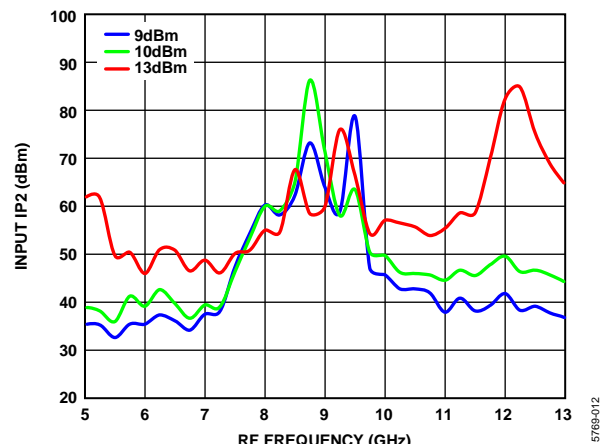


Figure 12. Input IP2 vs. RF Frequency at Various LO Powers

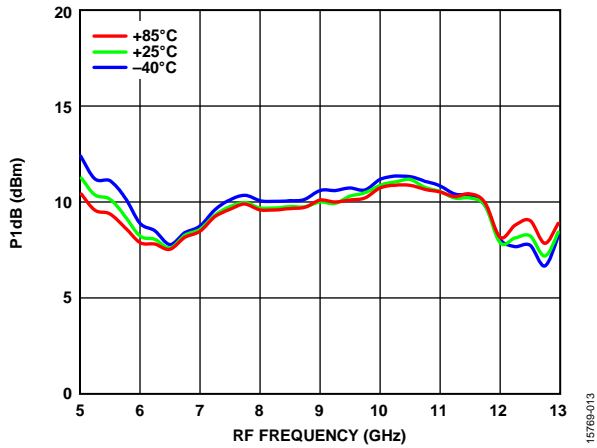


Figure 13. Input P1dB vs. RF Frequency at Various Temperatures

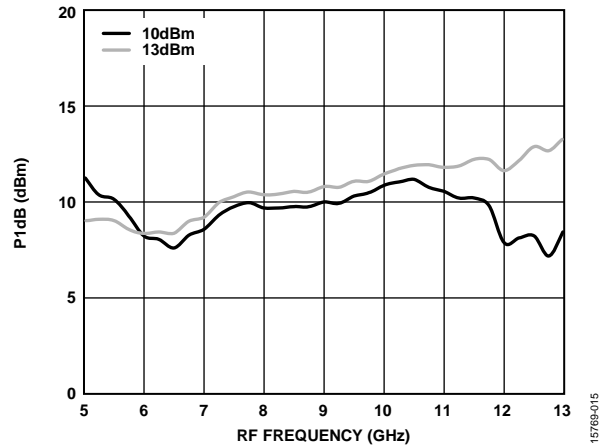


Figure 15. Input P1dB vs. RF Frequency at Various LO Powers

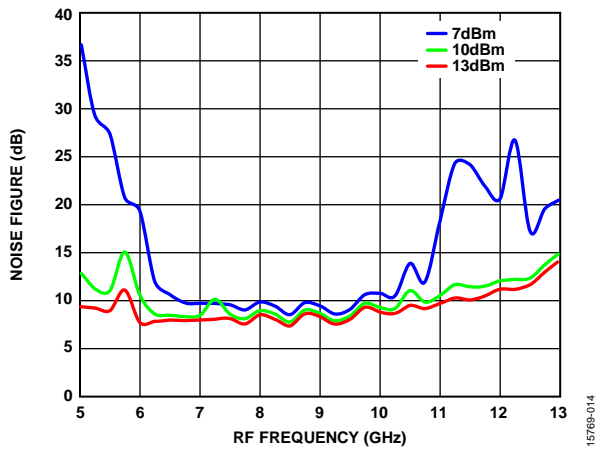


Figure 14. Noise Figure vs. RF Frequency at Various LO Powers

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157769-015

157769-014



**Downconverter Performance at IF = 1000 MHz, Lower Sideband**

Data taken at LO = 10 dBm, T<sub>A</sub> = 25°C, unless otherwise noted.

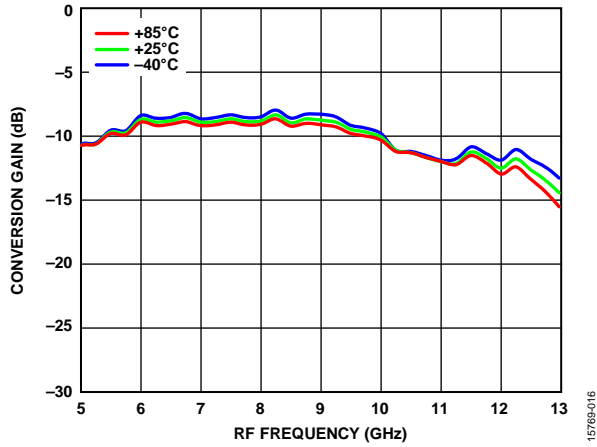


Figure 16. Conversion Gain vs. RF Frequency at Various Temperatures

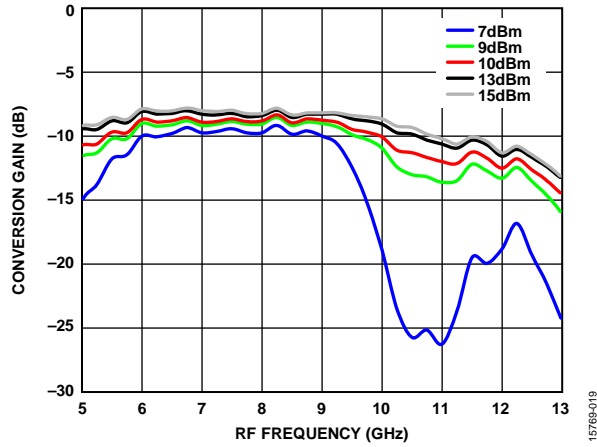


Figure 19. Conversion Gain vs. RF Frequency at Various LO Powers

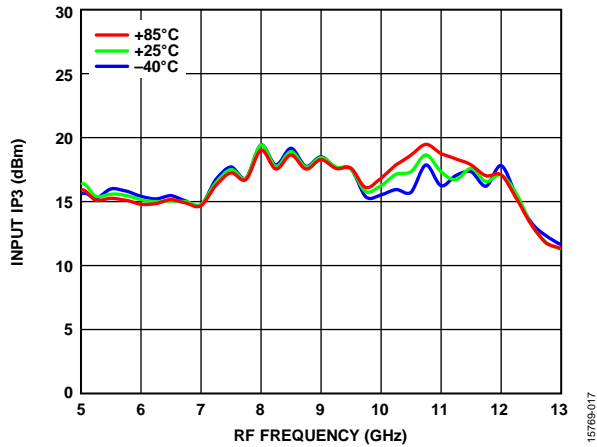


Figure 17. Input IP3 vs. RF Frequency at Various Temperatures

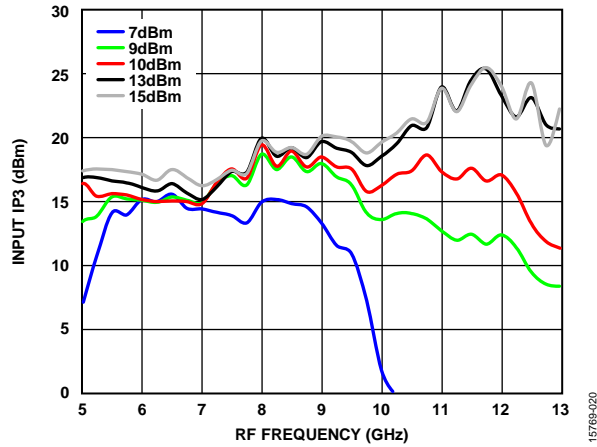


Figure 20. Input IP3 vs. RF Frequency at Various LO Powers

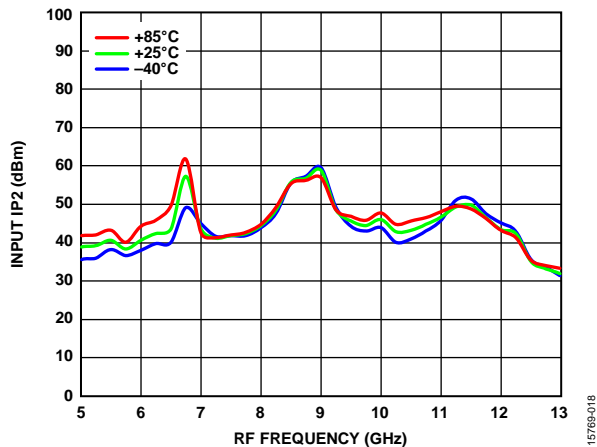


Figure 18. Input IP2 vs. RF Frequency at Various Temperatures

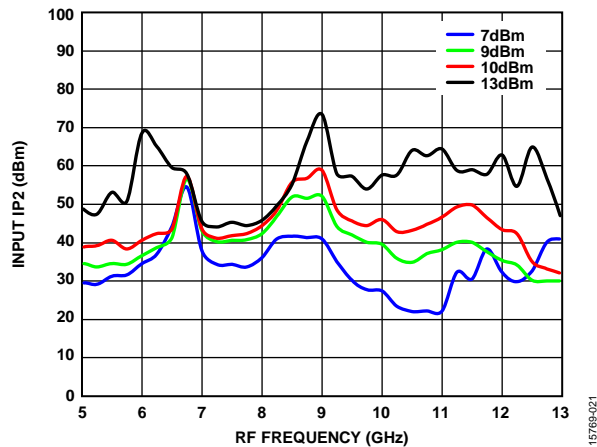


Figure 21. Input IP2 vs. RF Frequency at Various LO Powers

**Downconverter Performance at IF = 3000 MHz, Lower Sideband**

Data taken at LO = 10 dBm, T<sub>A</sub> = 25°C, unless otherwise noted.

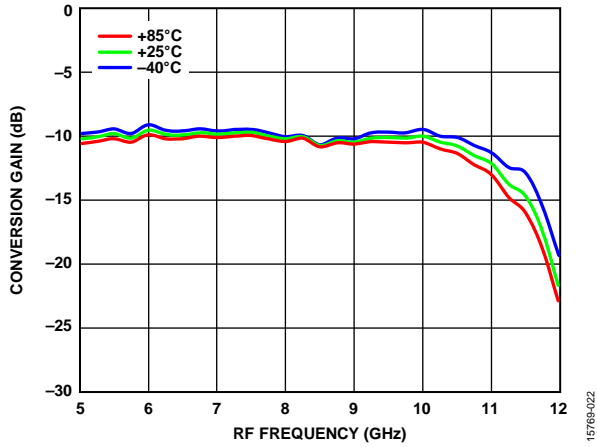


Figure 22. Conversion Gain vs. RF Frequency at Various Temperatures

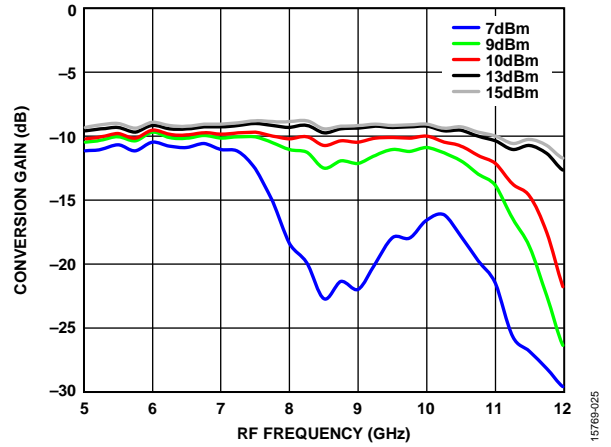


Figure 25. Conversion Gain vs. RF Frequency at Various LO Powers

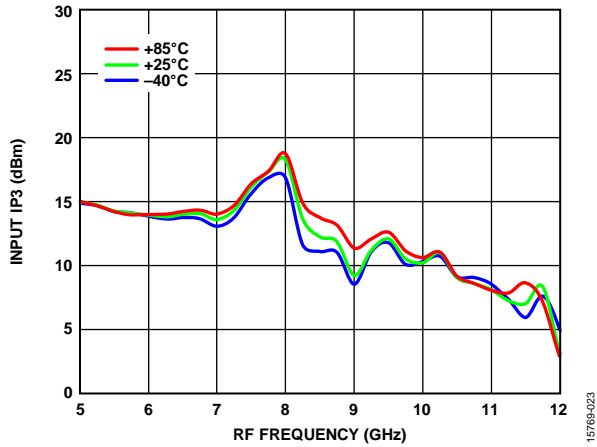


Figure 23. Input IP3 vs. RF Frequency at Various Temperatures

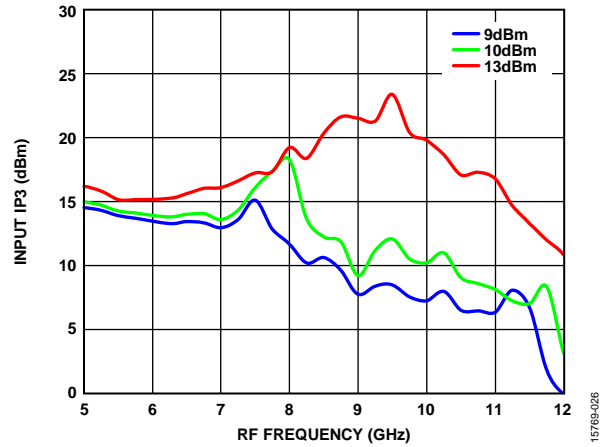


Figure 26. Input IP3 vs. RF Frequency at Various LO Powers

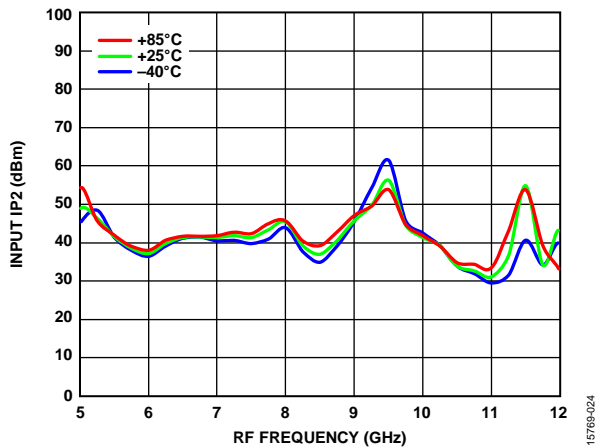


Figure 24. Input IP2 vs. RF Frequency at Various Temperatures

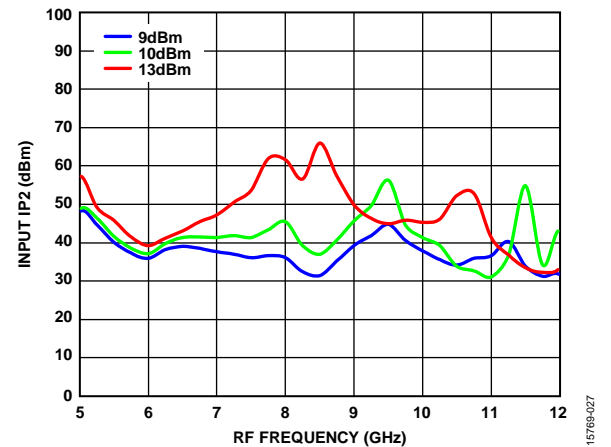


Figure 27. Input IP2 vs. RF Frequency at Various LO Powers

**UPCONVERTER PERFORMANCE**

**Upconverter Performance at IF = 100 MHz, Upper Sideband**

Data taken at LO = 10 dBm, T<sub>A</sub> = 25°C, unless otherwise noted.

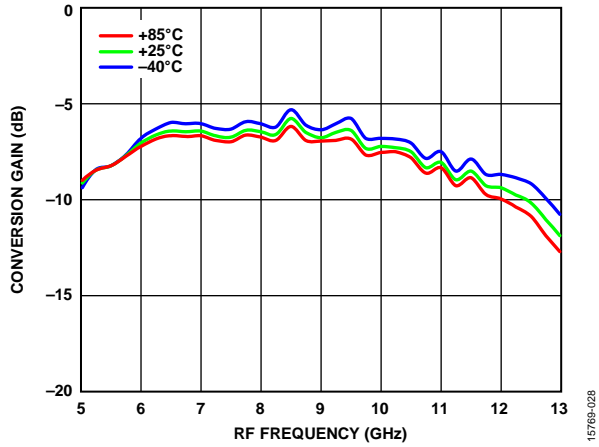


Figure 28. Conversion Gain vs. RF Frequency at Various Temperatures

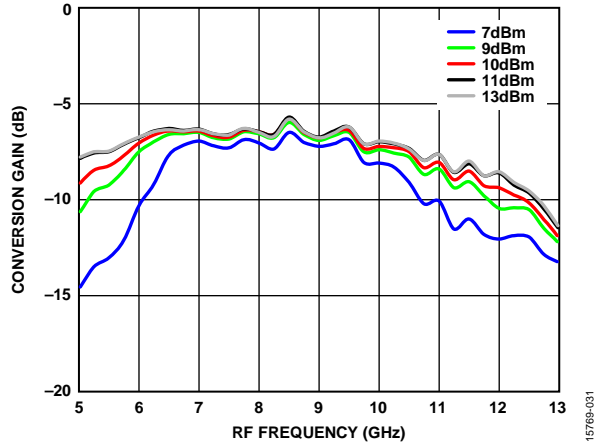


Figure 31. Conversion Gain vs. RF Frequency at Various LO Powers

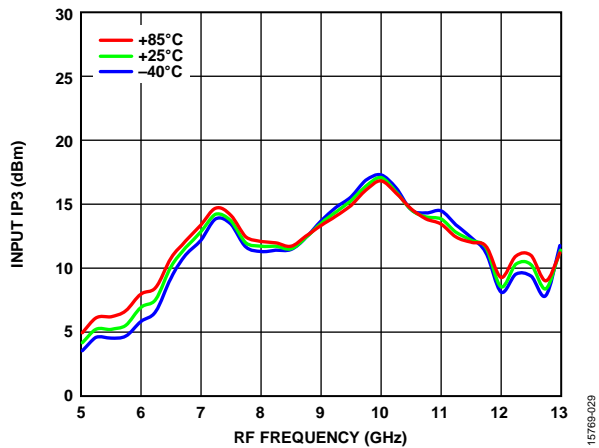


Figure 29. Input IP3 vs. RF Frequency at Various Temperatures

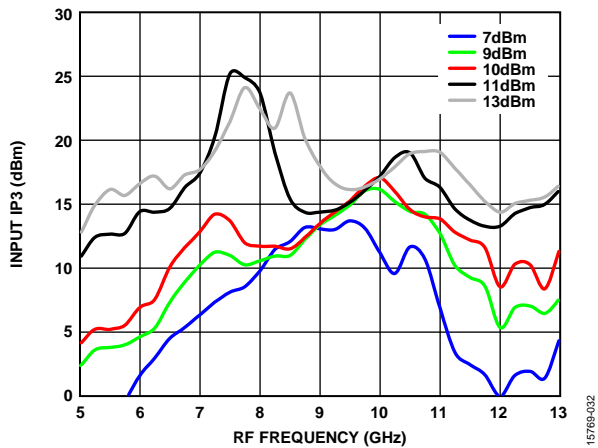


Figure 32. Input IP3 vs. RF Frequency at Various LO Powers

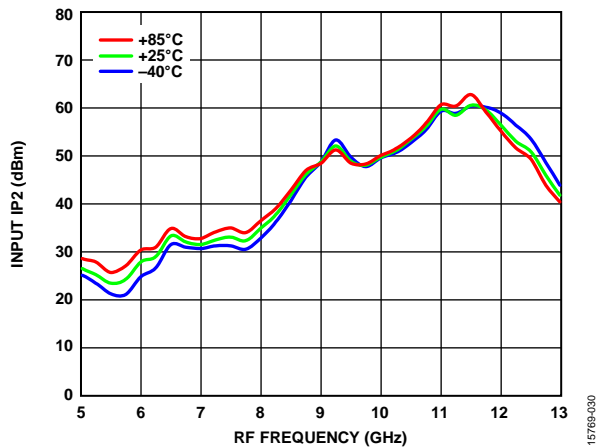


Figure 30. Input IP2 vs. RF Frequency at Various Temperatures

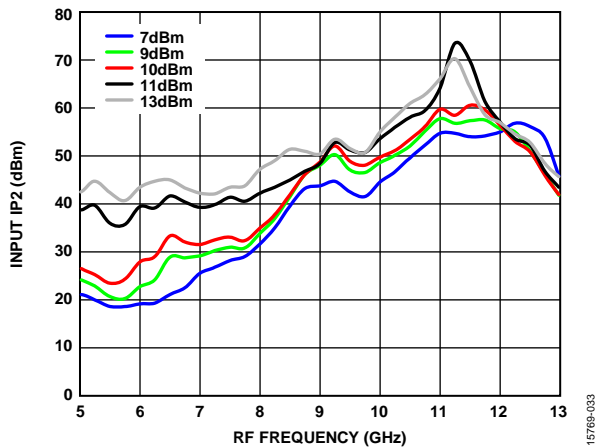


Figure 33. Input IP2 vs. RF Frequency at Various LO Powers

**ISOLATION AND RETURN LOSS**

Data taken at IF = 100 MHz, LO = 10 dBm,  $T_A = 25^\circ\text{C}$ , unless otherwise noted.

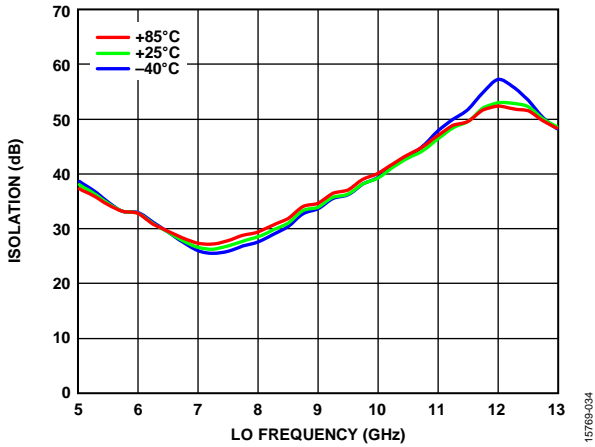


Figure 34. LO to IF Isolation vs. LO Frequency at Various Temperatures

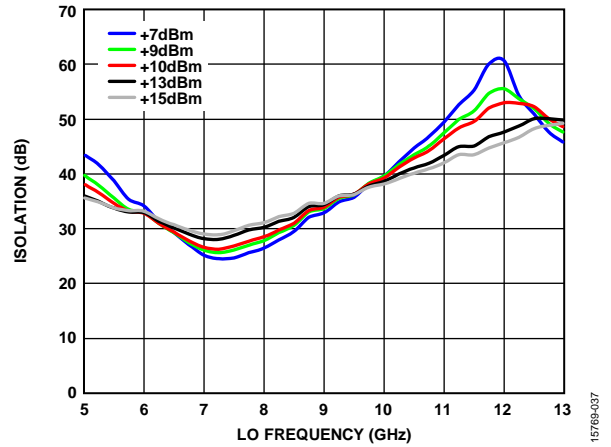


Figure 37. LO to IF Isolation vs. LO Frequency at Various LO Powers

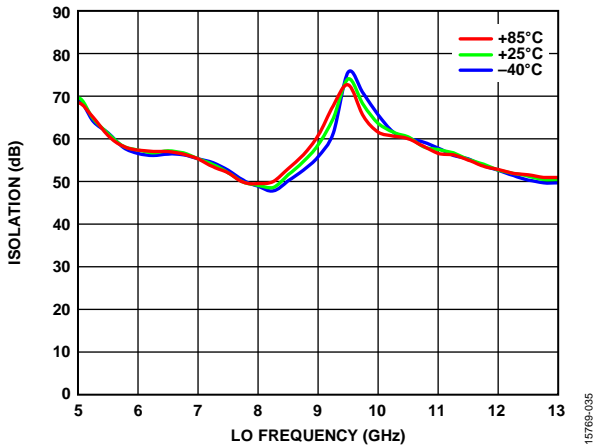


Figure 35. LO to RF Isolation vs. LO Frequency at Various Temperatures

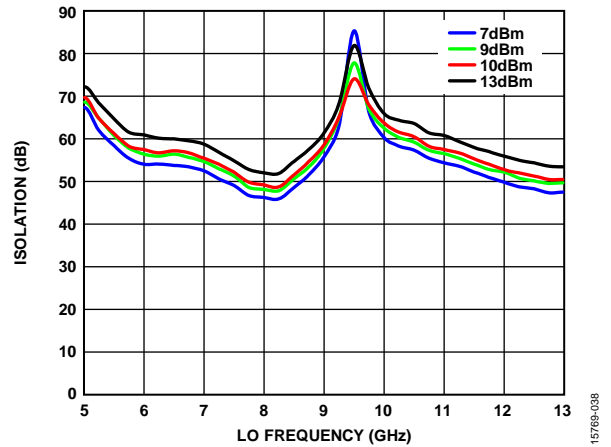


Figure 38. LO to RF Isolation vs. LO Frequency at Various LO Powers

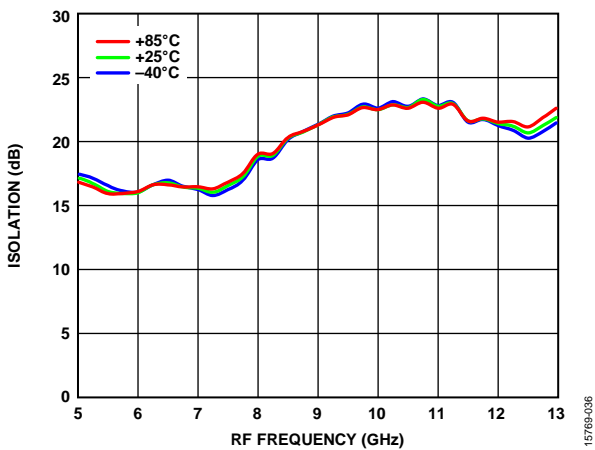


Figure 36. RF to IF Isolation vs. RF Frequency at Various Temperatures

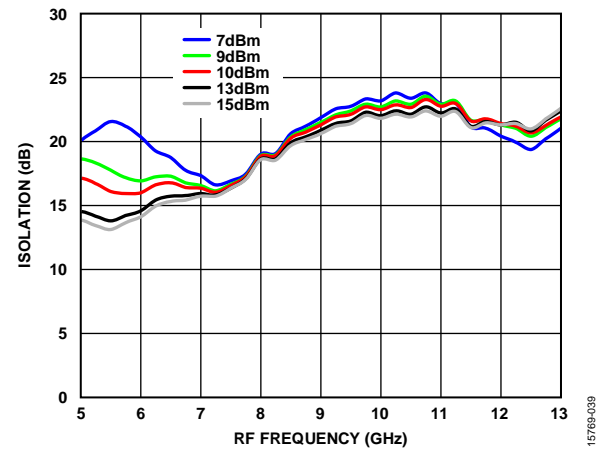


Figure 39. RF to IF Isolation vs. RF Frequency at Various LO Powers

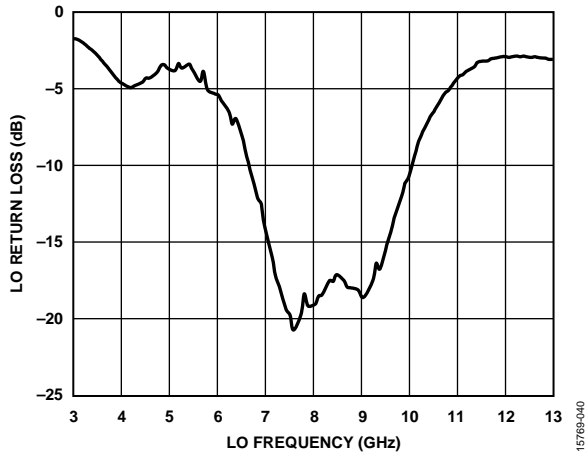


Figure 40. LO Return Loss vs. LO Frequency

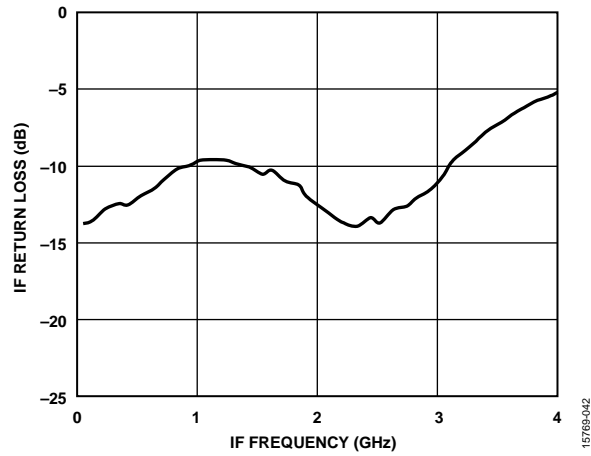


Figure 42. IF Return Loss vs. IF Frequency

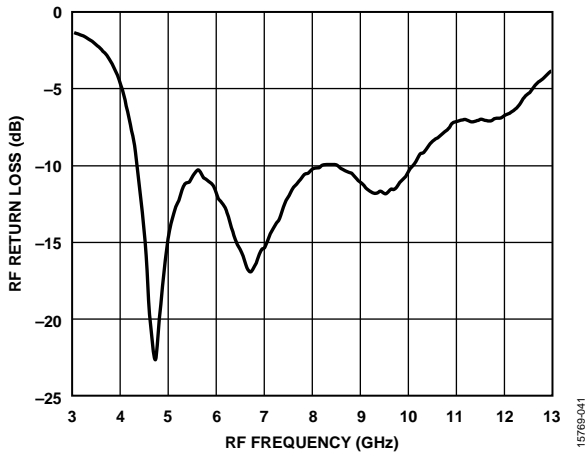


Figure 41. RF Return Loss vs. RF Frequency

**IF BANDWIDTH**

**Downconverter Performance, Lower Sideband**

Data taken at LO = 10 dBm, T<sub>A</sub> = 25°C, unless otherwise noted.

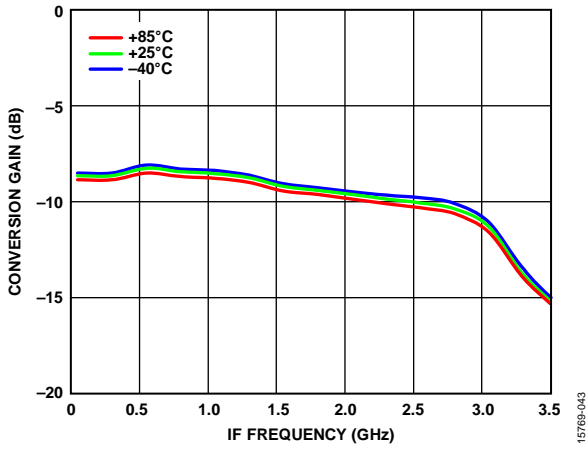


Figure 43. Conversion Gain vs. IF Frequency at Various Temperatures

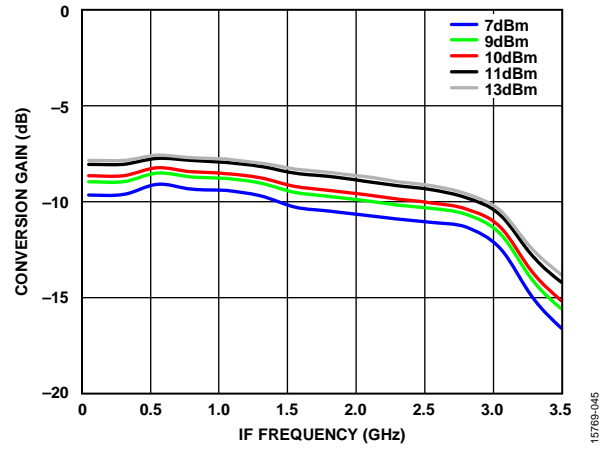


Figure 45. Conversion Gain vs. IF Frequency at Various LO Drives

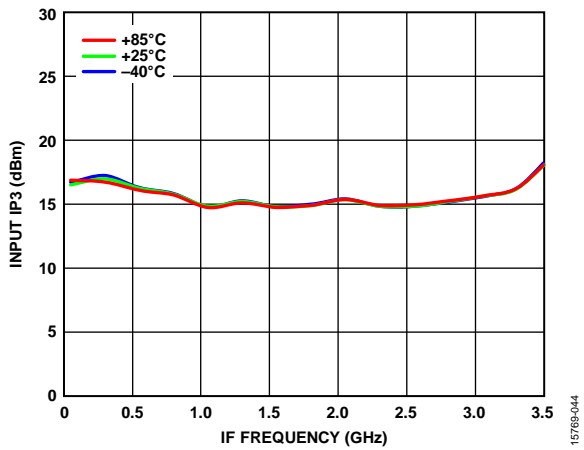


Figure 44. Input IP3 vs. IF Frequency at Various Temperatures

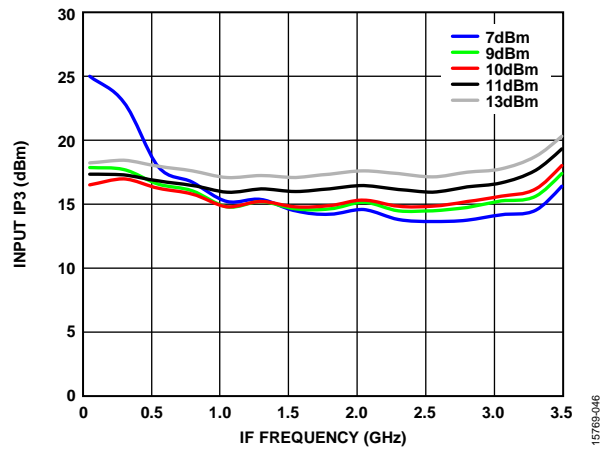


Figure 46. Input IP3 vs. IF Frequency at Various LO Drives

**Downconverter Performance, Upper Sideband**

Data taken at LO = 10 dBm, T<sub>A</sub> = 25°C, unless otherwise noted.

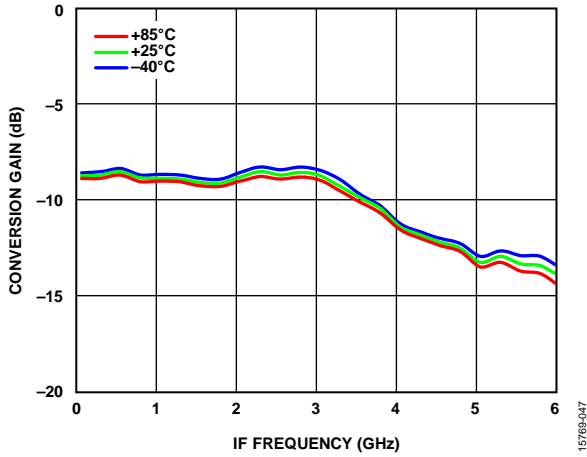


Figure 47. Conversion Gain vs. IF Frequency at Various Temperatures

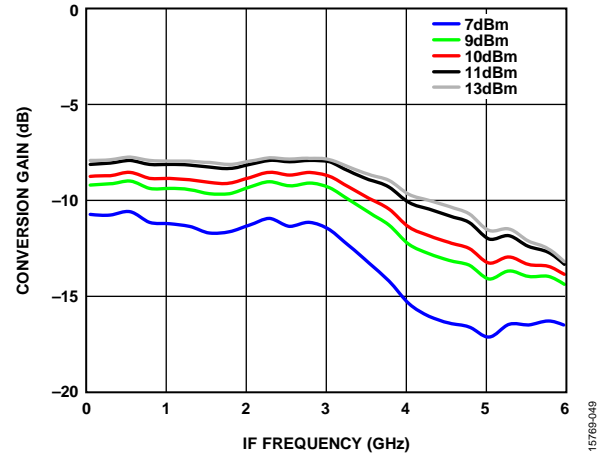


Figure 49. Conversion Gain vs. IF Frequency at Various LO Drives

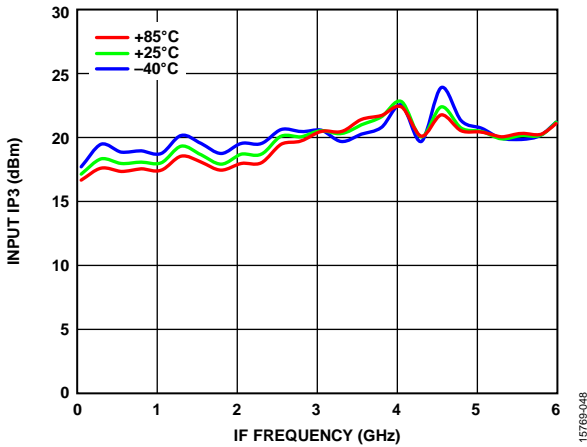


Figure 48. Input IP3 vs. IF Frequency at Various Temperatures

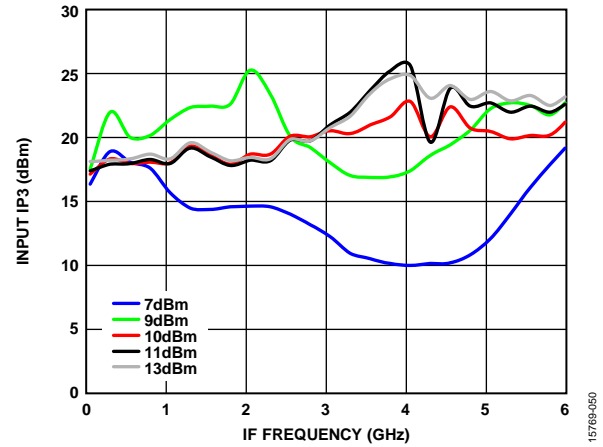


Figure 50. Input IP3 vs. IF Frequency at Various LO Drives

**SPURIOUS PERFORMANCE**

Mixer spurious products are measured in decibels relative to carrier from the IF output power level, unless otherwise noted.

Spur values are  $(M \times RF) - (N \times LO)$ .

**Harmonics of LO**

LO Power = 10 dBm. Values are in decibels relative to carrier (dBc) below the input LO level measured at the RF port.

LO Frequency (GHz)	N <sub>LO</sub> Spur at RF Port(dBc)			
	1	2	3	4
6	42	42	57	91
7	36	47	52	51
9	39	44	72	71
10	43	55	52	76
12	36	65	72	84
13	33	57	60	N/A <sup>1</sup>

<sup>1</sup> N/A means not applicable.

**M × N Spurious Outputs, IF = 100 MHz**

RF = 5000 MHz, LO = 5100 MHz, LO power = +10 dBm, RF power = -10 dBm.

M × RF	0	N × LO				
		1	2	3	4	5
	N/A <sup>1</sup>	7	25	31	52	56
1	5	0	12	29	40	43
2	57	63	60	62	64	71
3	77	60	49	50	52	65
4	83	85	88	89	88	84
5	82	84	85	87	79	78

<sup>1</sup> N/A means not applicable.

RF = 8500 MHz, LO = 8600 MHz, LO power = +10 dBm, RF power = -10 dBm.

M × RF	0	N × LO				
		1	2	3	4	5
	N/A <sup>1</sup>	2	28	29	54	46
1	12	0	23	46	68	50
2	80	49	57	46	83	82
3	88	82	75	69	68	85
4	82	87	88	89	96	86
5	80	85	86	88	95	95

<sup>1</sup> N/A means not applicable.

RF = 12000 MHz, LO = 12100 MHz, LO power = +10 dBm, RF power = -10 dBm.

M × RF	0	N × LO				
		1	2	3	4	5
	N/A <sup>1</sup>	20	35	39	56	0
1	9	0	26	59	62	61
2	85	63	69	80	86	75
3	75	84	77	61	77	86
4	62	76	87	89	94	89
5	0	63	75	85	87	95

<sup>1</sup> N/A means not applicable.

**M × N Spurious Outputs, IF = 1000 MHz**

RF = 5000 MHz, LO = 6000 MHz, LO power = +10 dBm, RF power = -10 dBm.

M × RF	0	N × LO				
		1	2	3	4	5
	N/A <sup>1</sup>	-3	+18	+31	+53	+46
1	-6	0	+6	+5	+27	+40
2	+41	+35	+31	+31	+35	+41
3	+40	+27	+5	+6	0	-6
4	+46	+53	+31	+18	-3	0
5	+67	+63	+39	+18	-3	-6

<sup>1</sup> N/A means not applicable.

RF = 8500 MHz, LO = 9500 MHz, LO power = +10 dBm, RF power = -10 dBm.

M × RF	0	N × LO				
		1	2	3	4	5
	N/A <sup>1</sup>	-3	+24	+28	+48	+49
1	+11	0	+21	+40	+62	+52
2	+88	+58	+60	+47	+64	+77
3	+87	+82	+84	+71	+72	+80
4	+84	+84	+90	+94	+95	+95
5	+81	+87	+87	+89	+87	+95

<sup>1</sup> N/A means not applicable.

RF = 12000 MHz, LO = 13000 MHz, LO power = +10 dBm, RF power = -10 dBm.

M × RF	0	N × LO				
		1	2	3	4	5
	N/A <sup>1</sup>	14	42	29	55	0
1	10	0	28	63	55	60
2	84	64	83	61	81	77
3	75	84	84	75	73	80
4	64	71	82	85	93	87
5	0	67	73	85	87	88

<sup>1</sup> N/A means not applicable.



## **THEORY OF OPERATION**

The HMC220B is a general-purpose, double balanced mixer in an 8-lead MINI\_SO\_EP, RoHS compliant package that can be used as an upconverter or a downconverter from 5 GHz to 12 GHz.

When used as a downconverter, the HMC220B downconverts RF between 5 GHz to 12 GHz to IF between dc and 4 GHz.

When used as an upconverter, the mixer upconverts IF between dc and 4 GHz to RF between 5 GHz and 12 GHz.

The mixer provides excellent LO to RF and LO to IF isolation due to optimized balun structures. The HMC220B requires no external components or matching circuitry. The RoHS compliant HMC220B eliminates the need for wire bonding and is compatible with high volume, surface-mount manufacturing techniques.

# APPLICATIONS INFORMATION

## EVALUATION PCB INFORMATION

The PCB used in this application must use RF circuit design techniques. Signal lines must have 50 Ω impedance, and the package ground lead and exposed pad must be connected directly to the ground planes. The evaluation PCB shown in Figure 52 is available from Analog Devices, Inc., upon request.

## TYPICAL APPLICATIONS CIRCUIT

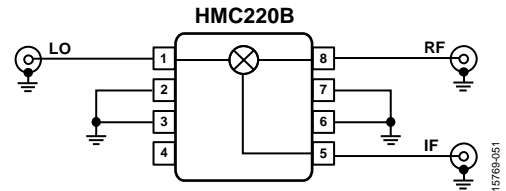


Figure 51. Typical Applications Circuit

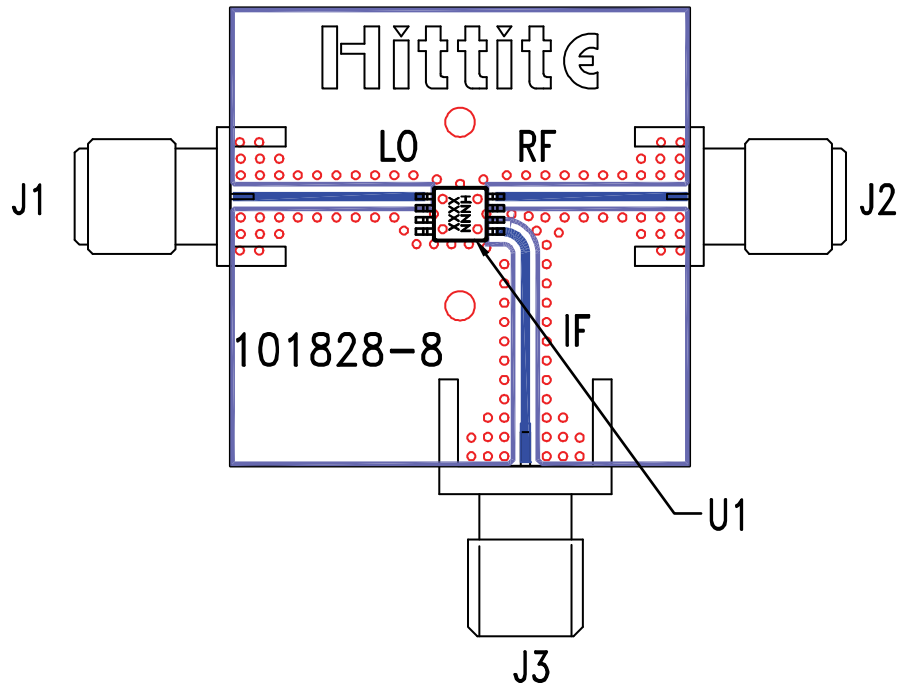
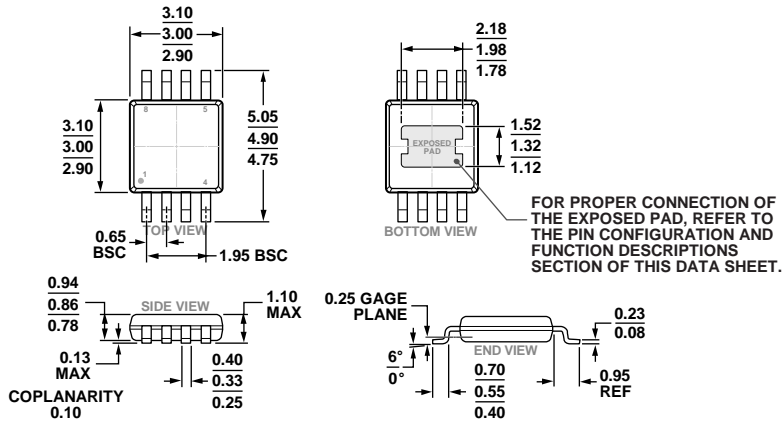


Figure 52. EV1HMC220BMS8G Evaluation PCB

Table 5. EV1HMC220BMS8G PCB Components

Item	Description	Reference Designator	Quantity	Manufacturer	Part Number
1	PCB, <a href="#">EV1HMC220BMS8G</a>		1	Analog Devices	101828-8
2	2.92 mm Subminiature Version A (SMA) connector	J1, J2	2	SRI Connector Gage	21-146-1000-01
3	SMA connector, end launch	J3	1	Cinch Connectivity Solutions Johnson	142-0701-851
4	Device under test (DUT)	U1	1	Analog Devices	HMC220BMS8GE

OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-187-AA-T

Figure 53. 8-Lead Mini Small Outline Package with Exposed Pad [MINI\_SO\_EP] (RH-8-3)  
Dimensions shown in millimeters

ORDERING GUIDE

Model <sup>1</sup>	Temperature Range	MSL Rating <sup>2</sup>	Package Description	Package Option	Branding <sup>3</sup>
HMC220BMS8GE	-40°C to +85°C	MSL1	Mini Small Outline Package with Exposed Pad [MINI_SO_EP]	RH-8-3	H220B XXXX
HMC220BMS8GETR	-40°C to +85°C	MSL1	Mini Small Outline Package with Exposed Pad [MINI_SO_EP]	RH-8-3	H220B XXXX
EV1HMC220BMS8G			Evaluation PCB Assembly		

<sup>1</sup> The HMC220BMS8GE and HMC220BMS8GETR are RoHS Compliant Parts.

<sup>2</sup> See the Absolute Maximum Ratings section.

<sup>3</sup> XXXX is the 4 digit lot number.